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#### NONSTOICHIOMETRY OF EPITAXIAL FeTiO348 FILMS

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#### **ABSTRACT**

Epitaxial thin films of (001)-oriented FeTiO<sub>3+δ</sub> were prepared on α-Al<sub>2</sub>O<sub>3</sub>(001) single crystalline substrates by helicon plasma sputtering technique. The FeTiO<sub>3+δ</sub> films had large oxygen nonstoichiometry, which seriously depended on both substrate temperature and oxygen pressure during the sputtering deposition. The valence states of Fe ions in FeTiO<sub>3+δ</sub> changed monotonically from Fe<sup>2+</sup> to Fe<sup>3+</sup> with decreasing the substrate temperature from 900 to 400°C or with increasing the oxygen pressure from 0.9 to  $1.8 \times 10^{-6}$  Pa. The change of Fe valence states from Fe<sup>2+</sup> to Fe<sup>3+</sup> induced the magnetic phase transition only for the films prepared at 900°C. The films containing Fe<sup>2+</sup> were paramagnetic while those with Fe<sup>3+</sup> were antiferromagnetic at room temperature. The oxygen nonstoichiometry of the FeTiO<sub>3+δ</sub> films was probably produced by cation vacancies and disarrangement of Fe<sup>3+</sup> and Ti<sup>4+</sup> ions, which randomly occupied both interstitial and substitutional sites of the FeTiO<sub>3</sub> related structure.

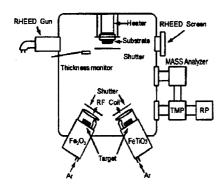
#### INTRODUCTION

Solid solutions of  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub>-FeTiO<sub>3</sub> (hematite-ilmenite) series are known to have interesting magnetic and electric properties [1,2]. Though the end members of this series are antiferromagnetic insulators, the intermediate compositions between them are half-metallic ferrimagnets. The compositions are nominally expressed as Fe<sup>3+</sup>2.2xFe<sup>2+</sup>xTi<sup>4+</sup>xO<sub>3</sub>, where x is the mole fraction of ilmenite. The crystal structure of them has rhombohedral symmetry and is considered as a slightly distorted hcp O<sup>2-</sup> framework with cations lying in two thirds of octahedral interstices in ordered way. We have recently succeeded in preparing well-crystallized epitaxial Fe<sub>2-x</sub>Ti<sub>x</sub>O<sub>3</sub> films by activated reactive evaporation [3,4]. The films of intermediate composites had large ferrimagnetic moments and their resistivity dropped to  $10^{-1}\Omega$ cm at room temperature. However the Fe<sup>2+</sup> content of the films was rather small as compared with stoichiometric Fe<sub>2-x</sub>Ti<sub>x</sub>O<sub>3</sub>. The Ti-rich films we previously prepared seemed to have large oxygen nonstoichiometry about  $\delta$ =0.3 in Fe<sub>2-x</sub>Ti<sub>x</sub>O<sub>3+δ</sub>.

Prior to preparing the stoichiometric solid-solution films of  $Fe_{2\cdot x}Ti_xO_3$ , we tried to confirm preparation conditions of stoichiometric FeTiO<sub>3</sub> films. According to a literature on bulk crystal growth of FeTiO<sub>3</sub> [5], very low oxygen pressure of about  $10^{-12}$  Pa is required to prevent the oxidization of  $Fe^{2+}$ . In the present study helicon plasma sputtering (magnetron sputtering assisted by inductively coupled RF plasma) technique was applied to prepare stoichiometric FeTiO<sub>3</sub>. The helicon plasma sputtering system we used had very high vacuum and low contaminations. The base pressure was less than  $10^{-7}$  Pa. The structural and magnetic properties of epitaxial FeTiO<sub>3+8</sub> films were reported as a function of the preparation conditions, *i.e.* stoichiometry of the films. The carefully controlled heating temperature and oxygen pressure should be essential to prepare stoichiometric films.

## **EXPERIMENT**

FeTiO<sub>3+δ</sub> films were prepared on α-Al<sub>2</sub>O<sub>3</sub>(001) single-crystalline substrates. Fig.1



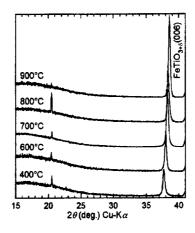


Figure 1. Schematic drawing of the helicon plasma sputtering system we used.

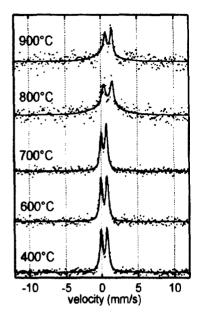
Figure 2. XRD patterns of FeTiO<sub>3+8</sub> films prepared on  $\alpha$ -Al<sub>2</sub>O<sub>3</sub>(001) substrates at different substrate temperatures.

shows a schematic drawing of the helicon plasma sputtering system we used. Two targets for helicon cathodes were made of sintered  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> and FeTiO<sub>3</sub>, respectively. In the present study only the FeTiO<sub>3</sub> target was operated. The base pressure of the system was  $10^{-7}$  Pa, and the oxygen partial pressure during the sputtering deposition was measured *in situ* by a mass analyzer unit. Before the sputtering deposition an  $\alpha$ -Al<sub>2</sub>O<sub>3</sub>(001) substrate was annealed in vacuum at about 900°C for 1 hour in order to obtain a clean and well-ordered surface. FeTiO<sub>3+δ</sub> films with the thickness of 100 nm were deposited on the substrates at various substrate temperatures ranging from 400 to 900°C. The deposited films were characterized by conventional θ-2θ x-ray diffraction (XRD) measurement, XRD pole figure measurement and conversion electron Mössbauer spectroscopy (CEMS). Chemical formula of prepared FeTiO<sub>3+δ</sub> films analyzed by energy dispersive X-ray spectroscopy (EDS) was Fe<sub>1,23</sub>Ti<sub>0,77</sub>O<sub>3+δ</sub>

### RESULTS AND DISCUSSION

#### Substrate Temperature

Fig.2 shows XRD patterns of the sample films prepared at various substrate temperatures between 400 and 900°C. All sample films showed only one intense diffraction line just beside a strong  $\alpha$ -Al<sub>2</sub>O<sub>3</sub>(006) line at 20=41.68°. It is well-known that FeTiO<sub>3</sub> has the same hcp O²- framework as  $\alpha$ -Al<sub>2</sub>O<sub>3</sub>, so the films could epitaxially formed on the substrates. Assuming the same lattice parameters as those of bulk FeTiO<sub>3</sub> crystals [6], the FeTiO<sub>3</sub>(006) diffraction line should appear at 20=38.29° which was very consistent with the observed 20 values for the sample films shown in Fig.2. Therefore the observed lines were indexed as FeTiO<sub>3+8</sub> (006). However the 20 values of FeTiO<sub>3+8</sub>(006) depended considerably on the substrate temperature when the films were prepared. With decreasing the substrate temperature the 20 value decreased gradually than that of the bulk FeTiO<sub>3</sub> crystals. Moreover the line intensity was decreased in addition to the line broadening. The calculated grain size by using a Scherrer's equation was typically 325 Å at



**Table I.** Fitted parameters for CEMS spectra shown in Fig. 3.

Substrate temperature (°C)	Isomer shifts (mm/s)	Quadropole splitting (mm/s)
900	1.13	0.98
800	1.03	1.14
700	0.37	0.73
600	0.37	0.87
400	0.35	0.85

Figure 3. Room temperature CEMS spectra of FeTiO<sub>3+8</sub> films prepared at different substrate temperatures.

900°C and 260 Å at 400°C, respectively.

Room temperature CEMS spectra of sample films prepared at various substrate temperatures are shown in Fig.3. All sample films were paramagnetic. Assuming the analyzed chemical formula of  $Fe_{1.23}Ti_{0.77}O_3$ , the Néel temperature of stoichiometric films should be about  $-25^{\circ}C$  [1], i.e. below the room temperature. The magnetic properties seemed to be consistent with those of bulk crystals. But the valence states of Fe ions evaluated from the Mössbauer isomer shifts showed considerable changes depending on the substrate temperature. The films prepared at higher substrate temperature consisted of  $Fe^{2+}$  ions, while those at lower substrate temperature consisted of  $Fe^{3+}$  ions. The isomer shifts of sample films gradually increased with increasing the substrate temperature. The quadropole splitting also reflected the valence states of Fe ions.  $Fe^{2+}$  ions, which had a remnant orbital angular momentum in crystal fields, normally gave larger quadupole splitting than  $Fe^{3+}$  ions.

### Oxygen Pressure

The 20 values of FeTiO<sub>3+8</sub>(006) seriously depended on the oxygen pressure during the sputtering deposition. Fig.4 shows the 20 values for sample films prepared at the substrate temperature of 900°C as a function of the oxygen pressure. With increasing the oxygen pressure the 20 value increased from literature values for stoichiometric Fe<sup>2+</sup>TiO<sub>3</sub> [6] to  $\alpha$ -Fe<sup>3+</sup>2O<sub>3</sub> [7]. There were small possibilities that the FeTiO<sub>3+8</sub> films decomposed into two phases like  $\alpha$ -Fe<sub>2</sub>O<sub>3</sub> and TiO<sub>2</sub>, because the diffraction lines of FeTiO<sub>3+8</sub>(006) maintained sharp profiles and no diffraction lines due to the secondary phases appeared when oxygen pressure was increased.

Room temperature CEMS spectra of sample films prepared at various oxygen pressures are shown in Fig.5. The spectrum with a paramagnetic doublet at lower oxygen pressure

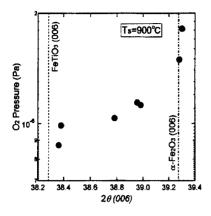
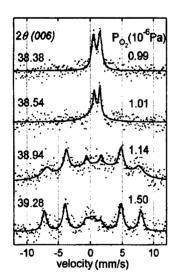


Figure 4. 20 values for FeTiO<sub>3+ $\delta$ </sub> films prepared at 900°C as a function of the oxygen pressure during the sputtering deposition.

changed to magnetically split sextet patterns at higher oxygen pressure. The Néel temperature of sample films increased gradually above room temperature. Moreover the valence states of Fe ions evaluated from the Mössbauer isomer shifts changed from  $Fe^{2+}$  to  $Fe^{3+}$  with increasing the oxygen pressure.  $Fe^{3+}$  (S=5/2) ions had a larger spin magnetic moment than  $Fe^{2+}$  (S=2) ions. Therefore the formation of  $Fe^{3+}$  ions from  $Fe^{2+}$  ions raised the Néel temperature of the films.

The increased oxygen pressure and the decreased substrate temperature seemed to produce same effects on the iron valence states of the FeTiO<sub>3+ $\delta$ </sub> films. However the 2 $\theta$  values of FeTiO<sub>3+ $\delta$ </sub>(006) gave the contrary results depending on the respective preparation conditions. The oxidized films owing to the increased oxygen pressure showed the increased the 2 $\theta$  values, while the films prepared at the decreased substrate temperature had the decreased 2 $\theta$  values. This contradictory was probably due to the inferior crystallinity of the FeTiO<sub>3+ $\delta$ </sub> films prepared at lower



**Table II.** Fitted parameters for CEMS spectra shown in Fig. 5.

2θ value (deg.)	Isomer shifts (mm/s)	Quadropole splitting (mm/s)	Hyperfine field (kOe)
38.38	1.02	1.01	•
38.54	0.82	0.88	-
38.94	0.50	-	449.9
39.28	0.40	_	470.5

Figure 5. Room temperature CEMS spectra of FeTiO<sub>3+ $\delta$ </sub> films prepared at different oxygen pressures.

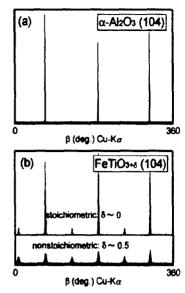


Figure 6.  $\beta$ -scan profiles for (104) pole figures of (a) an  $\alpha$ -Al<sub>2</sub>O<sub>3</sub> substrate and (b) stoichiometric and nonstoichiometric FeTiO<sub>3+8</sub> films.

substrate temperature. The films prepared at lower substrate temperature earned small crystallization energy and loosened the lattice structures. The inferior crystallinity of sample films maintained the paramagnetic properties though the films contained Fe<sup>3+</sup> ions with larger spin magnetic moment.

### Crystal Structure

It was very interesting to know the crystal structure of nonstoichiometric FeTiO<sub>3+δ</sub>. In oxidation studies of FeTiO<sub>3</sub> bulk crystals, nonstoichiometric FeTiO<sub>3+δ</sub> easily decomposed into stable phases of Fe<sub>2</sub>TiO<sub>5</sub> and TiO<sub>2</sub>, or Fe<sub>2</sub>Ti<sub>3</sub>O<sub>9</sub> and Fe<sub>2</sub>O<sub>3</sub> [8]. As far as we know, the nonstoichiometric FeTiO<sub>3+8</sub> was not observed in a bulk form. An epitaxial relationship between the  $\alpha$ -Al<sub>2</sub>O<sub>3</sub> substrate and the FeTiO<sub>3+8</sub> film was obtained by XRD pole figures. Fig.6 shows the B-scan profiles of (104) diffraction lines for the α-Al<sub>2</sub>O<sub>3</sub> substrate, the stoichiometric Fe<sup>2+</sup>TiO<sub>3</sub> film, and the nonstoichiometric Fe3+TiO3+8 film. According to the crystal symmetries of corundum and ilmenite structures, the (104) poles should have three-hold symmetry and appeared in every 120° for β-scan. The β-scan profiles clearly suggested that the stoichiometric FeTiO<sub>3</sub> film had nearly the same in-plane symmetry as that for the corundum or ilmenite structure. However the (104) poles for the nonstoichiometric FeTiO<sub>3+δ</sub> film had six-hold symmetry because the diffraction lines appeared in every 60°. The change of in-plane symmetry for nonstoichiometric FeTiO<sub>3+δ</sub> suggested the redistribution of cation occupancies in octahedral interstices of hcp oxygen layers. Fe3+and Ti4+ ions randomly occupied both interstitial and substitution sites in the ilmenite-related structure. And cation vacancies were introduced into the structure to maintain the charge neutrality. The disordered cation occupancies we proposed here were already reported in Sn-, Ti-, and Mg-substituted α-Fe<sub>2</sub>O<sub>3</sub> [9].

### **ACKNOWLEDGEMENT**

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### REFERENCES

- 1. Y. Ishikawa, J. Phys. Soc. Jpn. 17, p.1835 (1962).
- 2. Y. Ishikawa, J. Phys. Soc. Jpn. 13, p.37 (1958).
- 3. T.Fujii, K. Ayama, M. Nakanishi, and J. Takada, J. Magn. Soc. Jpn. 22, S1, p.206 (1998).
- 4. T. Fujii, K. Ayama, M. Nakanishi, M. Sohma, K. Kawaguchi, and J. Takada, Mat. Res. Soc. Symp. Proc. 623, p.191 (2000).
- 5. R. K. Pandey, S. Sunkara, and J. Muthusami, AIP Conf. Proc. 361, p.193 (1996)
- 6. Powder diffraction files, JCPDS 29-733.
- 7. Powder diffraction files, JCPDS 33-664.
- 8. R.A. Briggs and A.Sacco Jr., Meal. Trans. 24A, p.1257 (1993).
- 9. F.J. Berry, C. Greaves, Ö. Helgason, J. McManus, H.M. Palmer, and R.T. Williams, J. Solid State Chem. 151, p.157 (2000).